

Temperature programmed molecular dynamics (TPMD) method

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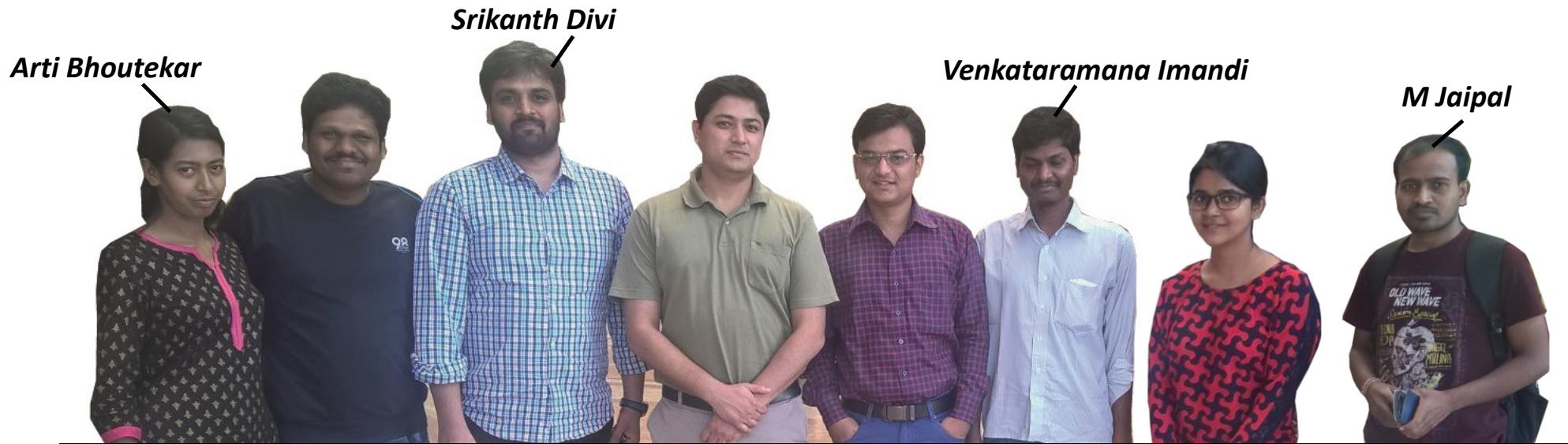
- [1] Divi and Chatterjee, JCP, 140, 184115 (2014)
- [2] Chatterjee and Bhattacharya, JCP, 2015
- [3] Venkaramana and Chatterjee, JCP 2016**

Funding: Department of Science and Technology (DST),
Indian National Science Academy (INSA)



Students

- Missing in group photo below: Paramita Haldar, Mohit Prateek



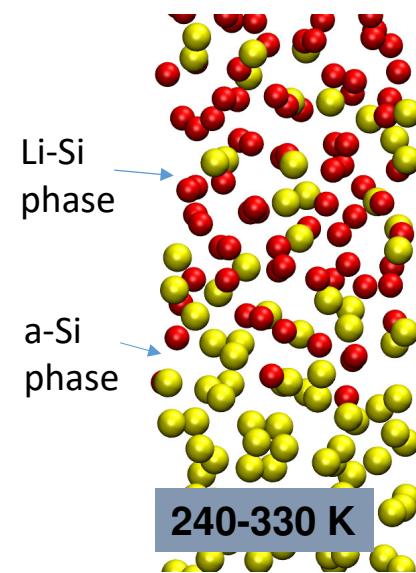
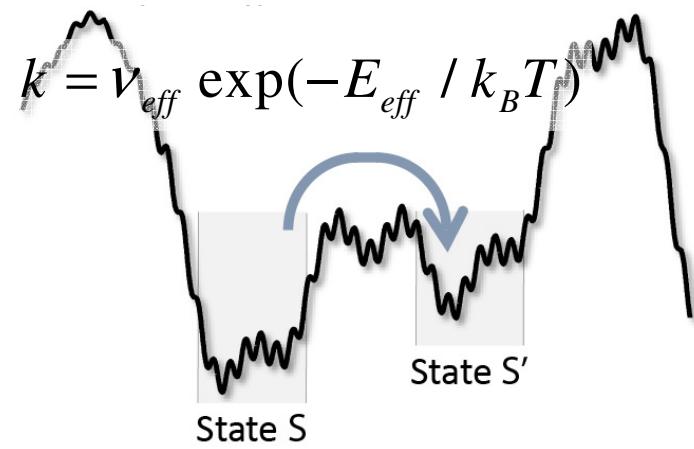
Collaborators

- Prof. Swati Bhattacharya, IIT Guwahati
- Prof. Arindam Sarkar, IIT Bombay



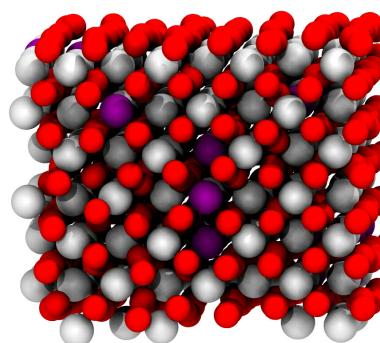
Building KMC models with TPMD... ... some key features of TPMD

POTENTIAL ENERGY LANDSCAPE

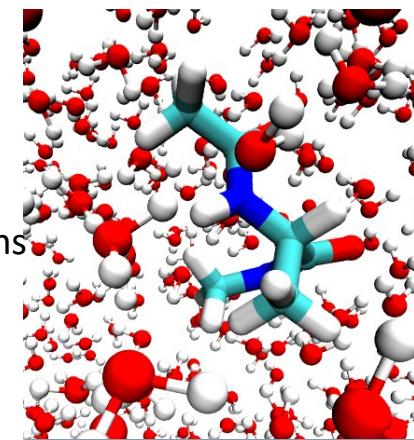


Phase transformations
during lithiation and
delithiation in Si
(lithium ion battery
anode material)

800-1200 K



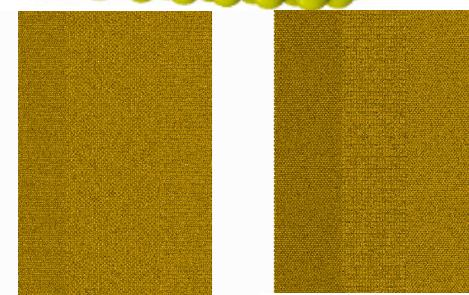
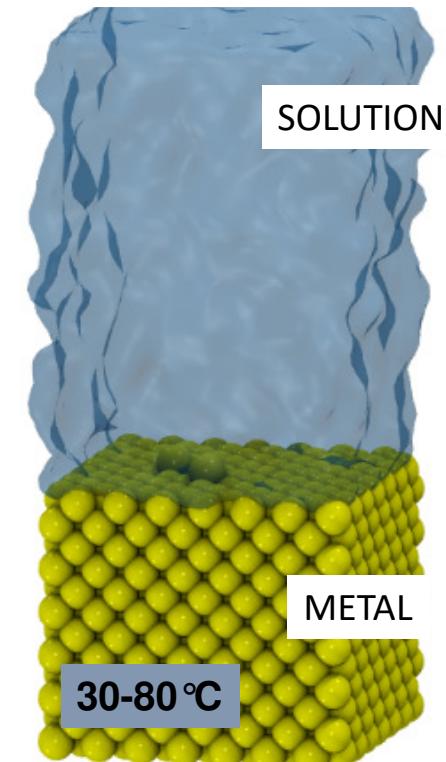
Ion conducting oxides
(yttria stabilized zirconia)



Room temperature

Biomolecular systems
(with Prof. S. Bhattacharya)

SOLUTION

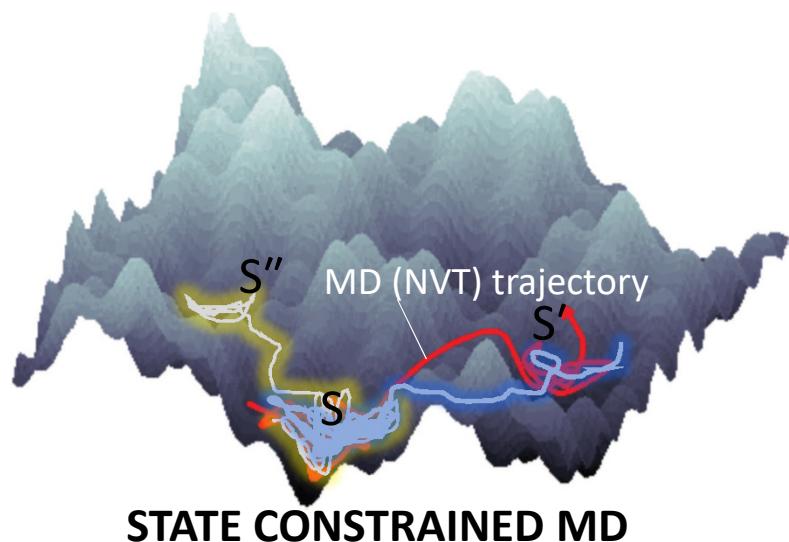


Selective dissolution in
metal alloys: Long-time
evolution 30-80 °C

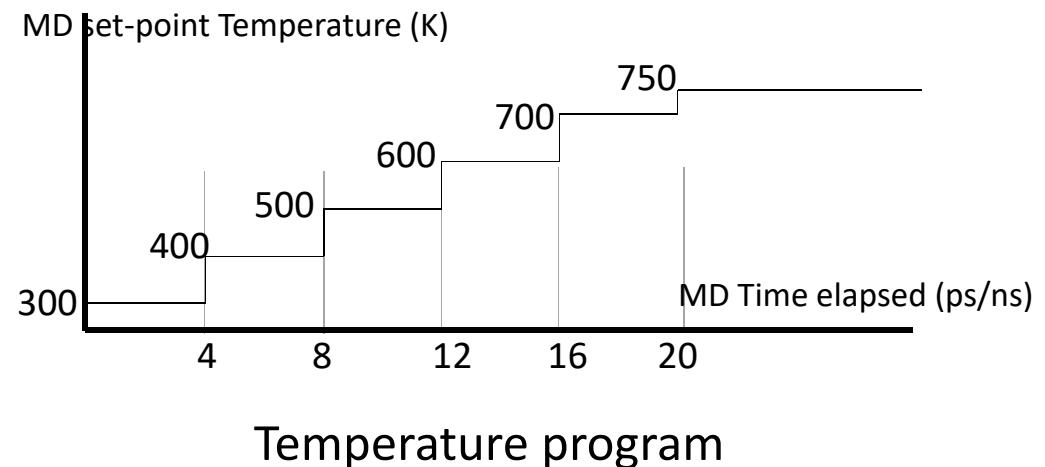


Steps involved in building KMC model using TPMD

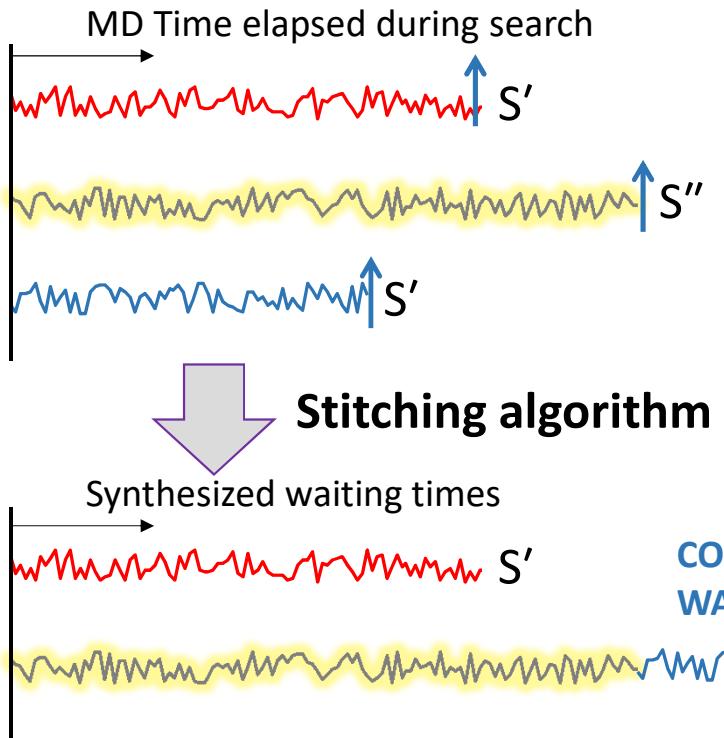
- *Efficiently find states, pathways/rates over a range of temperatures*
- *Probe whether Arrhenius assumption is reasonable and find effective Arrhenius parameters*



State (collection of potential energy basins)

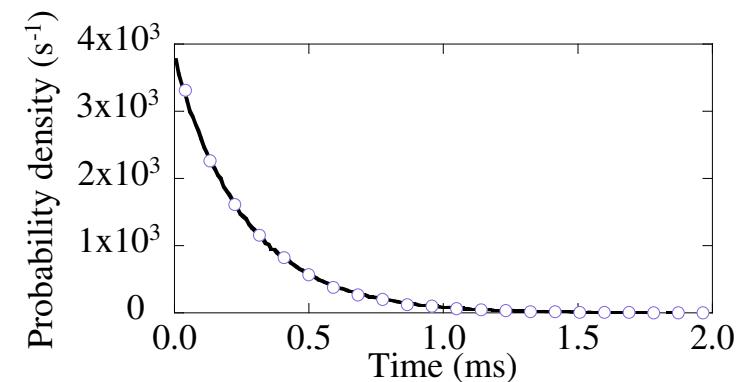
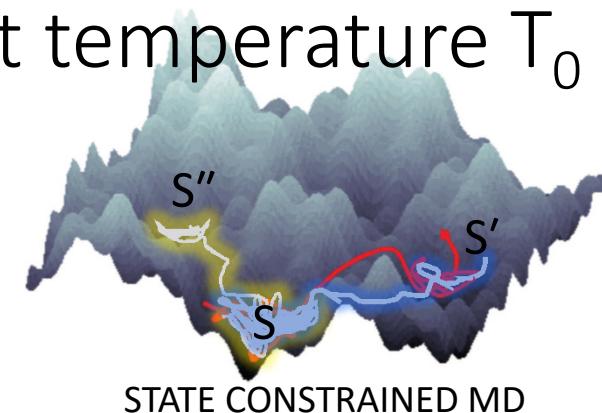


Rate estimation in MD @ constant temperature T_0



$$P(t)dt = \exp(-k_\alpha^0 t) k_\alpha^0 dt$$

Probability of no escape in time $[0, t]$ \times Probability of escape in time $[t, t+dt]$



Maximum likelihood estimate for rate constant

$$k_\alpha^0 = \frac{n}{\tau_\alpha}$$

CONS: RARE EVENTS ARE POORLY SAMPLED



Temperature programmed MD

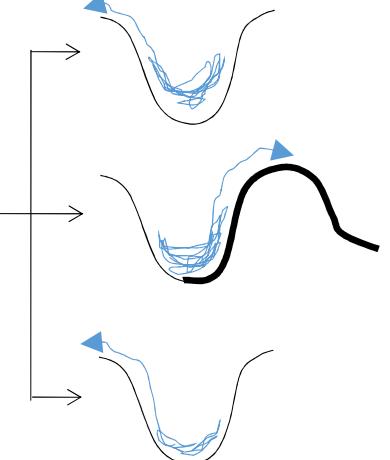
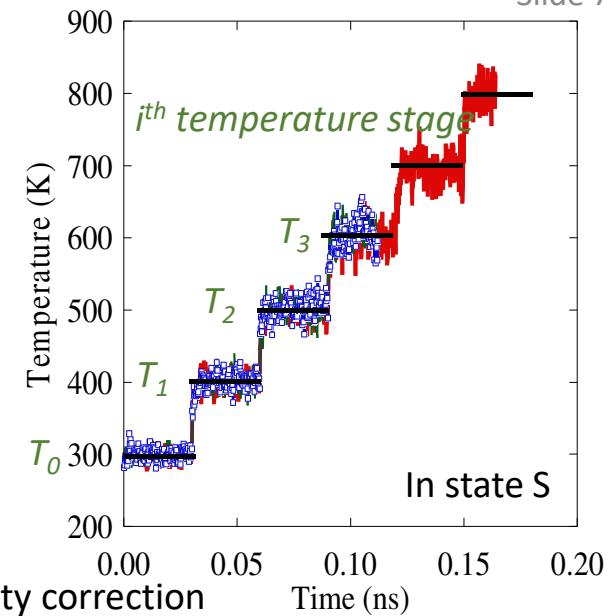
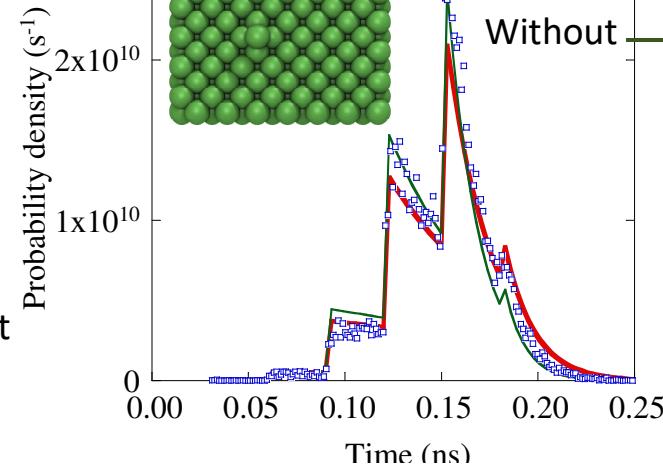
- Increase temperature in steps
- Langevin thermostat is employed
- Kinetic pathways can be sought in parallel

TPMD distribution

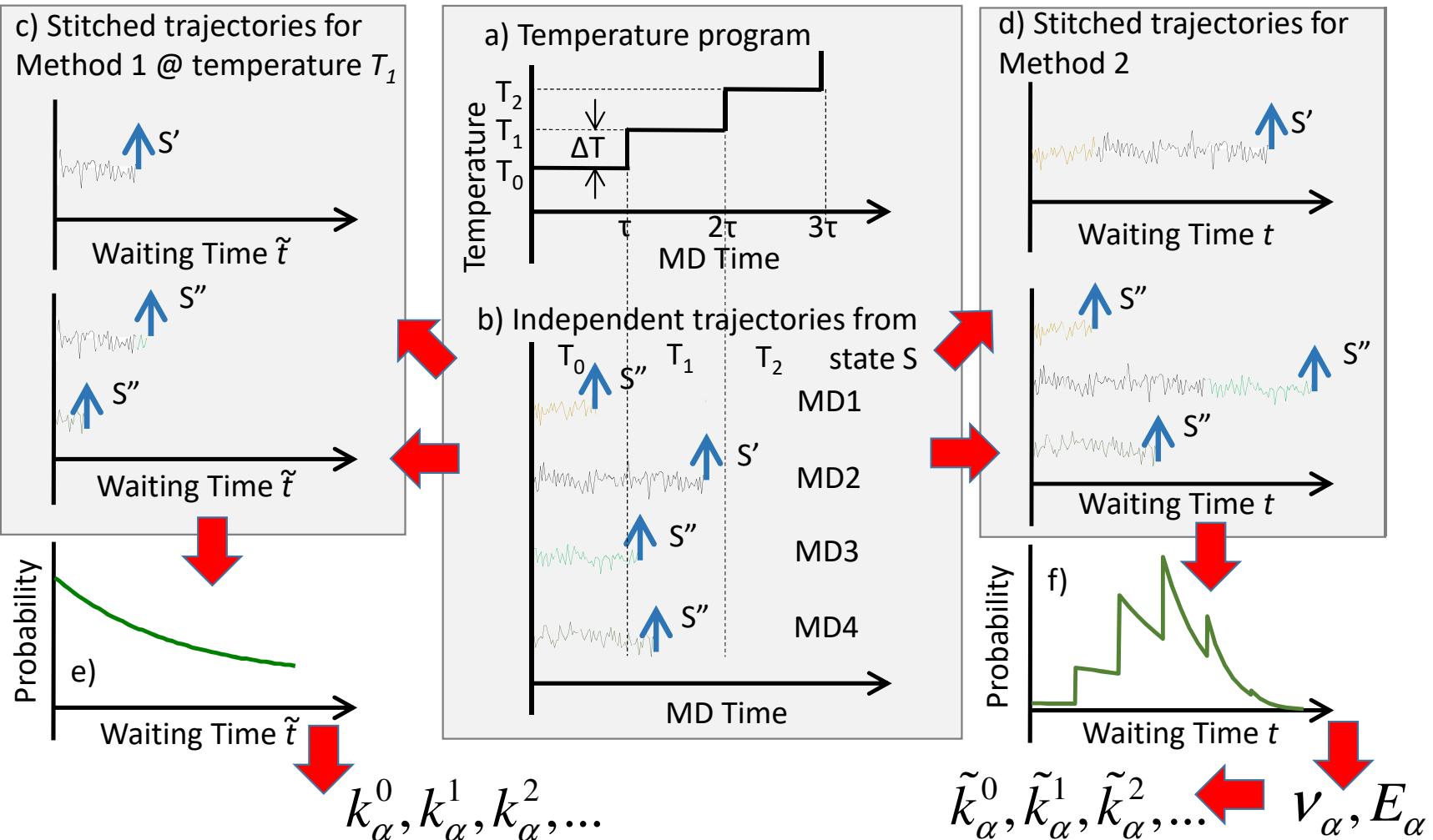
$$P(t) = \left[\prod_{i=0}^n \exp(-k_\alpha^i \tau_i) \right] k_\alpha^n dt,$$

$$n\tau < t \leq (n+1)\tau$$

Dynamically relevant pathways selected with higher probability at low temperatures



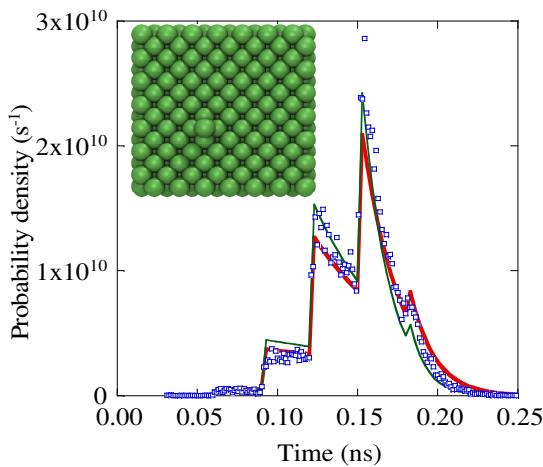
Estimating rates at different temperatures



Estimating effective Arrhenius parameters for a pathway

- Assume Arrhenius behavior for the pathway

$$k_{\alpha}^0 = v_{\alpha} \exp\left(\frac{-E_{\alpha}}{k_B T_0}\right)$$



Collection of waiting times

$\{\tilde{t}_1, \tilde{t}_2, \dots, \tilde{t}_m\}$

$$\frac{\sum_{i=0}^{N_{\max}} \theta_i T_i^{-1} \exp(-E_{\alpha} / k_B T_i)}{\sum_{i=0}^{N_{\max}} \theta_i \exp(-E_{\alpha} / k_B T_i)} = T_X^{-1}$$

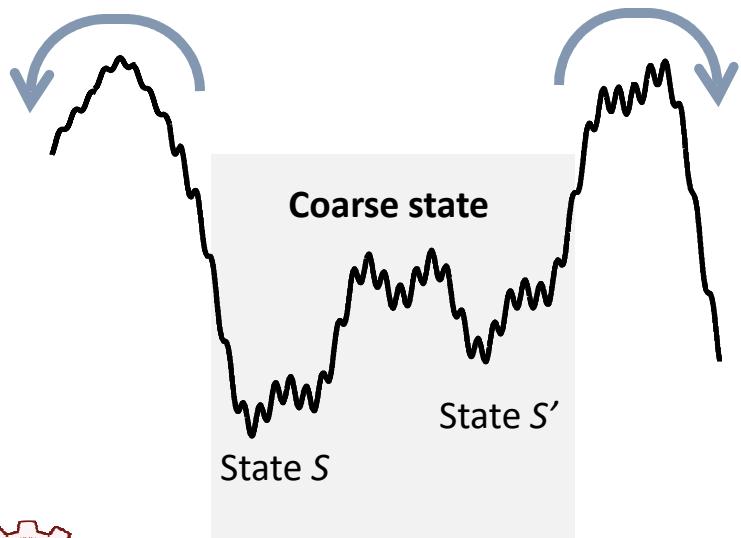
$$V = \frac{m}{\sum_{i=0}^{N_{\max}} \theta_i \exp(-E_{\alpha} / k_B T_i)}$$

$$T_X = m / \sum_{\alpha=1}^m T_{n\alpha}^{-1}$$



Waiting time distribution for coarse-states

- Double benefit from TPMD
 - Overcoming large activation barriers
 - Access low probability states



$$p(t) = \pi_{s,n} k_n \prod_{i=1}^{N_{\max}} \exp(-\pi_{s,i} k_i \tau_i)$$

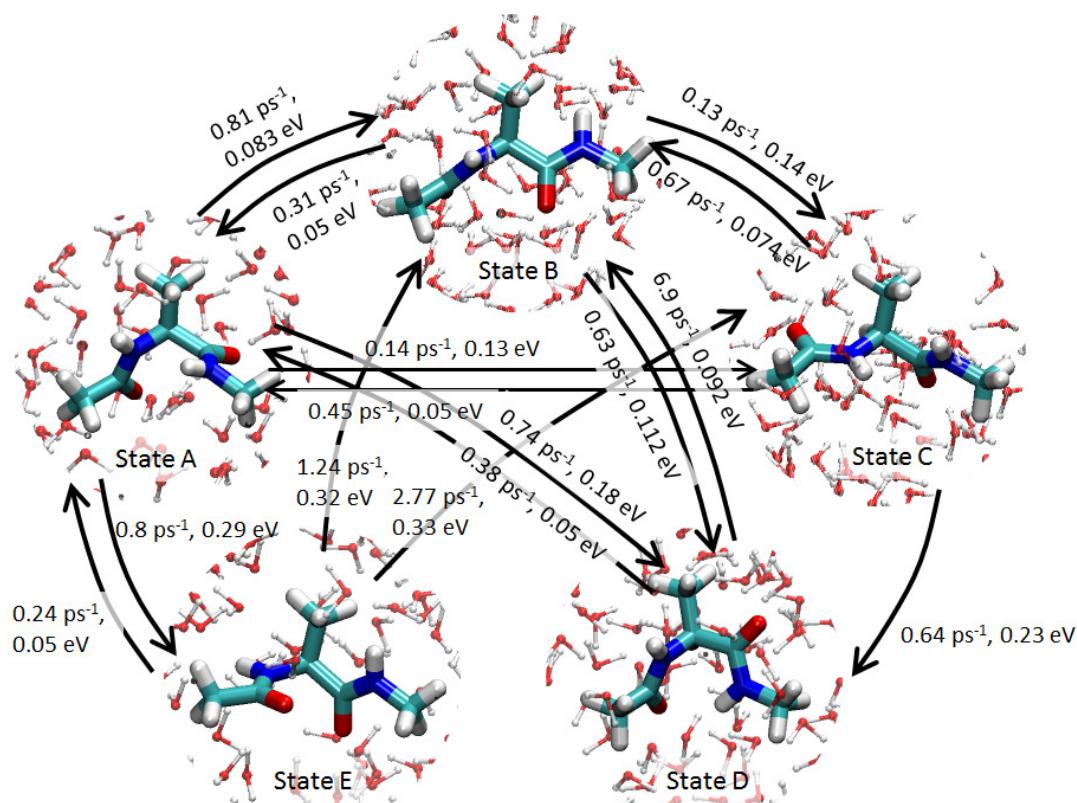
$$\frac{d\pi}{dt} = T\pi$$

$$\frac{\sum_{i=0}^{N_{\max}} \pi_{s,i} \theta_i T_i^{-1} \exp(-E_\alpha / k_B T_i)}{\sum_{i=0}^{N_{\max}} \pi_{s,i} \theta_i \exp(-E_\alpha / k_B T_i)} = T_X^{-1}$$

$$V = \frac{m}{\sum_{i=0}^{N_{\max}} \pi_{s,i} \theta_i \exp(-E_a / k_B T_i)}$$

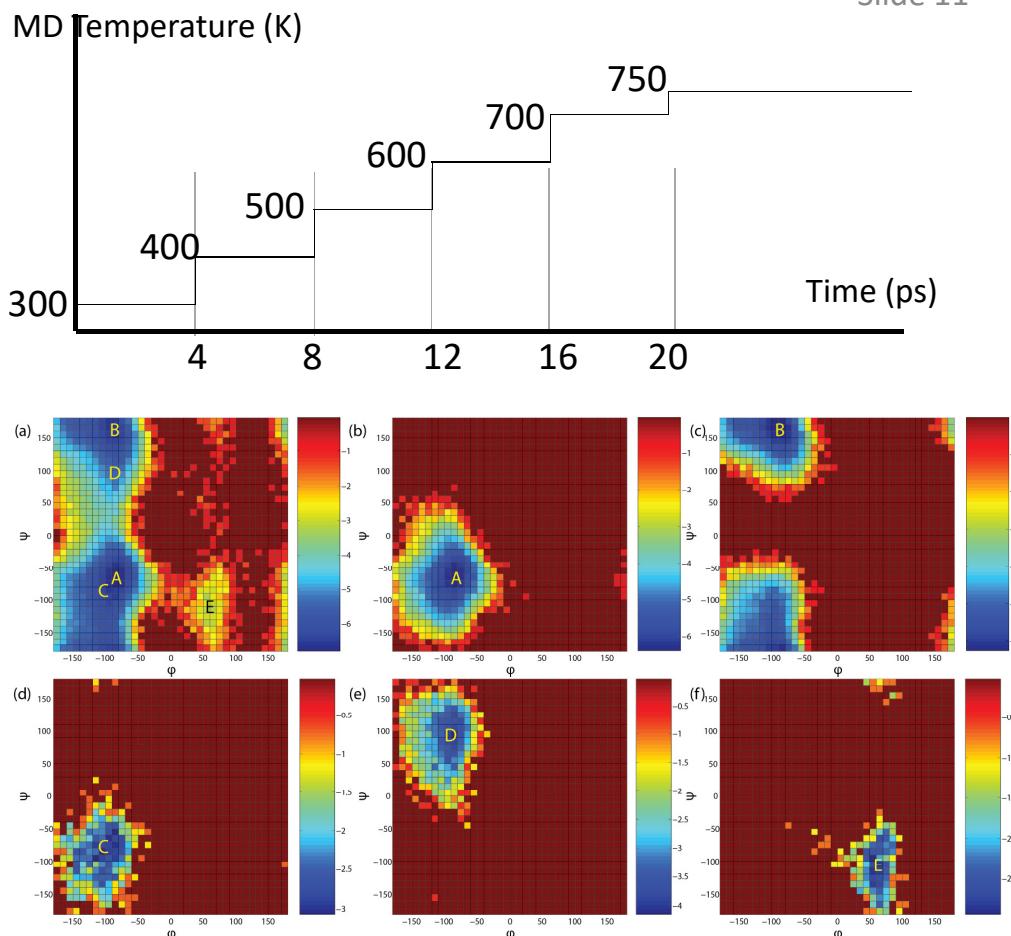


Example: Alanine dipeptide



MARKOV STATE MODEL FOR ALANINE DIPEPTIDE

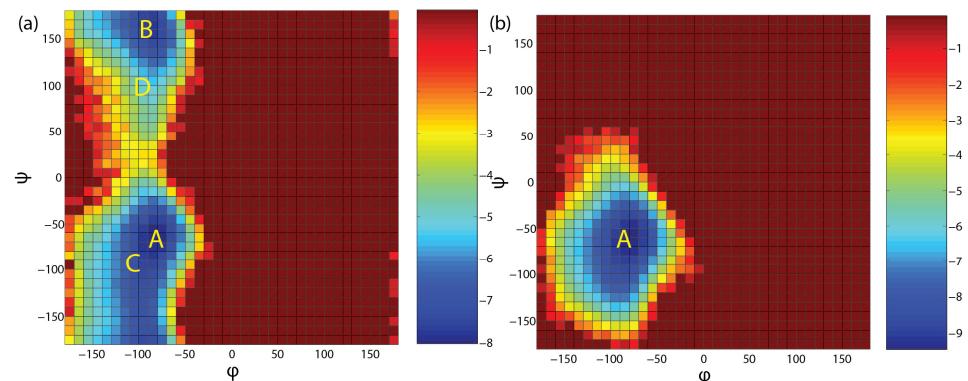
with Prof. S. Bhattacharya, IIT Guwahati



Free energy map @ 600 K

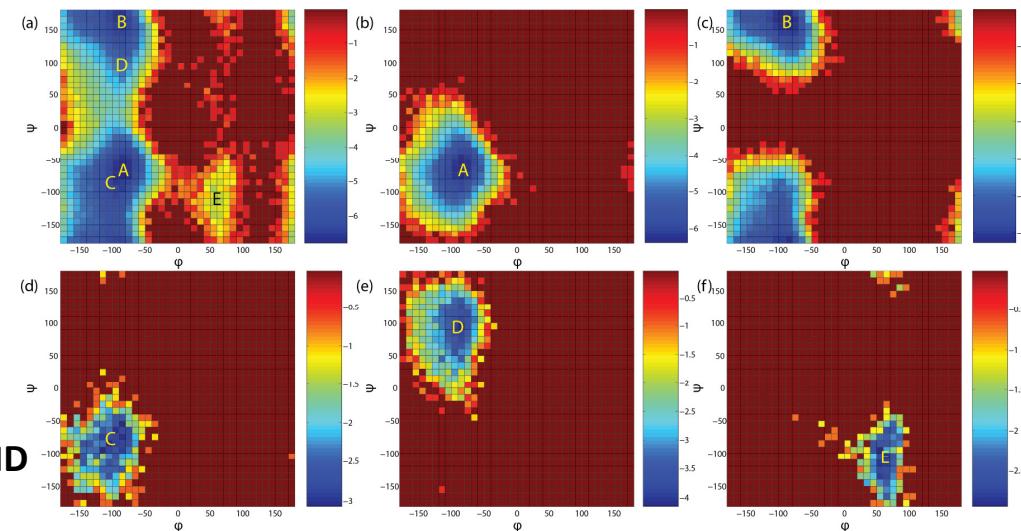
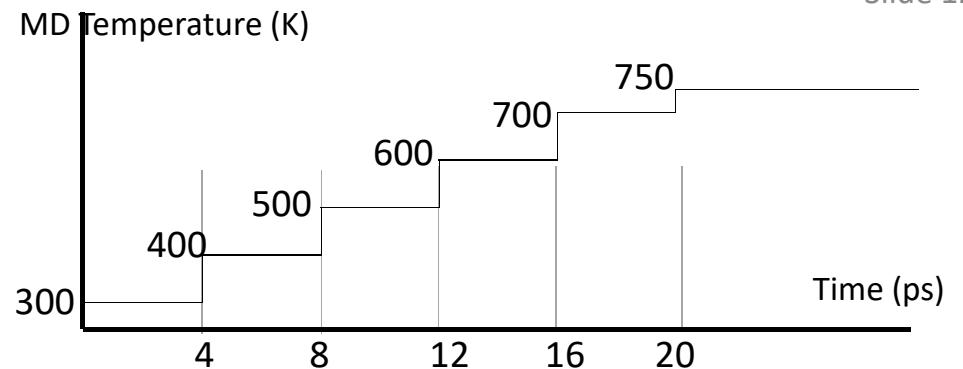
NOTE: WE DON'T EMPLOY FREE ENERGY MAPS IN TPMD

Example: Alanine dipeptide



Free energy map @ 300 K

NOTE: WE DON'T EMPLOY FREE ENERGY MAPS IN TPMD



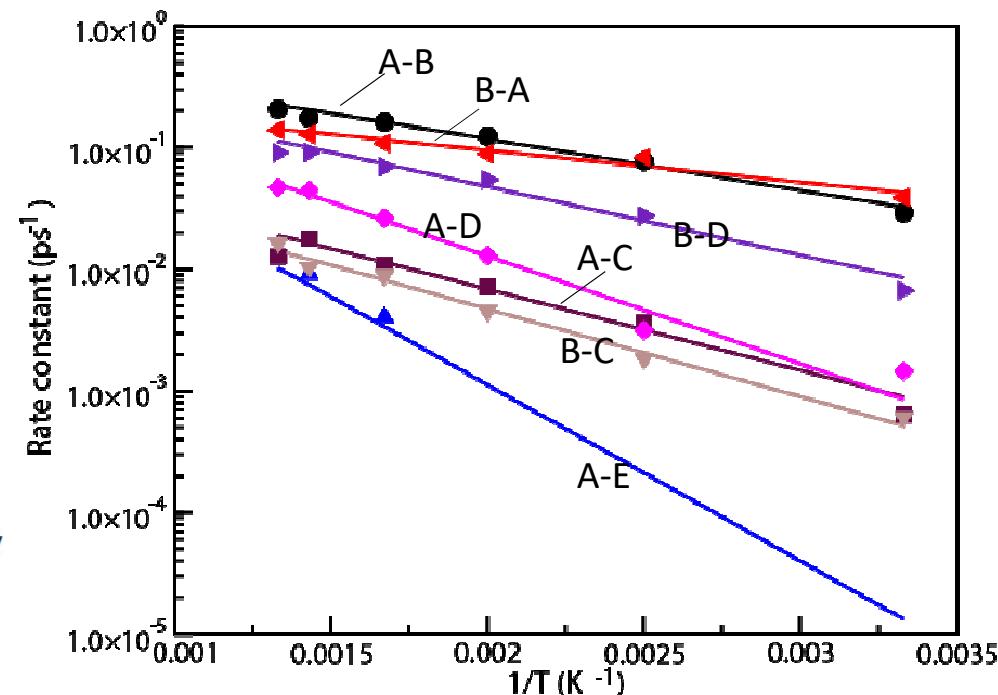
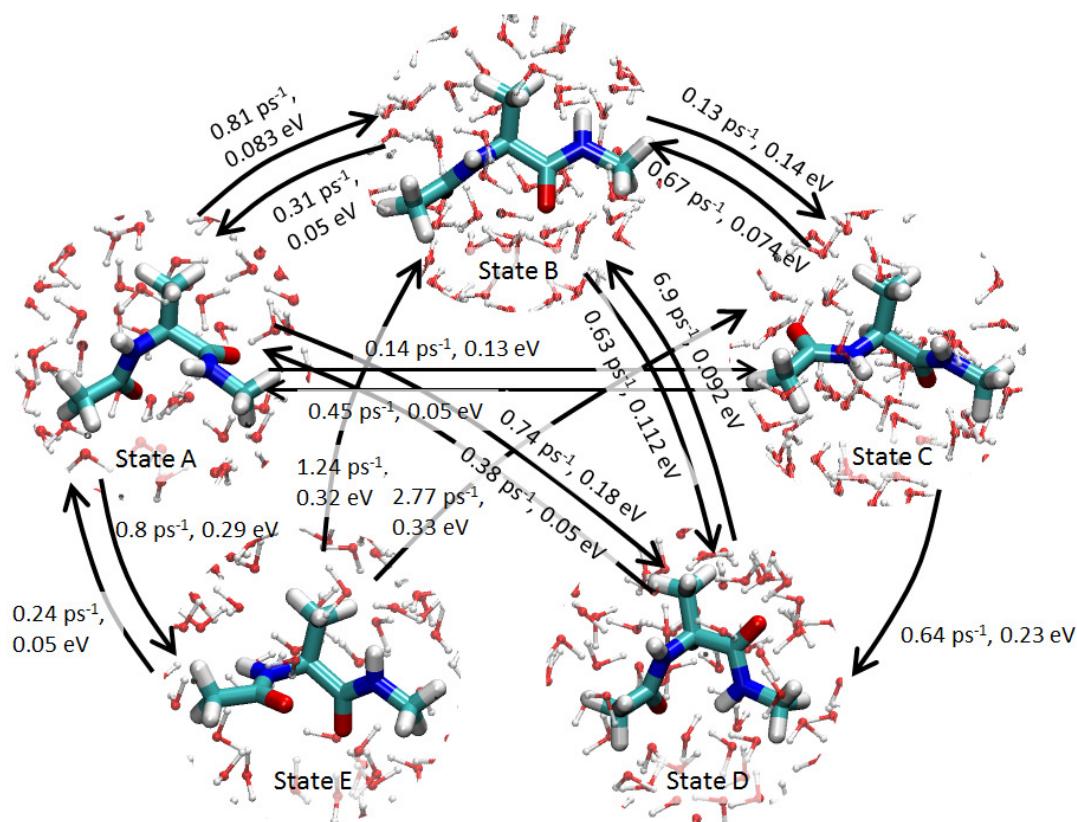
Free energy map @ 600 K

NOTE: WE DON'T EMPLOY FREE ENERGY MAPS IN TPMD



with Prof. S. Bhattacharya, IIT Guwahati

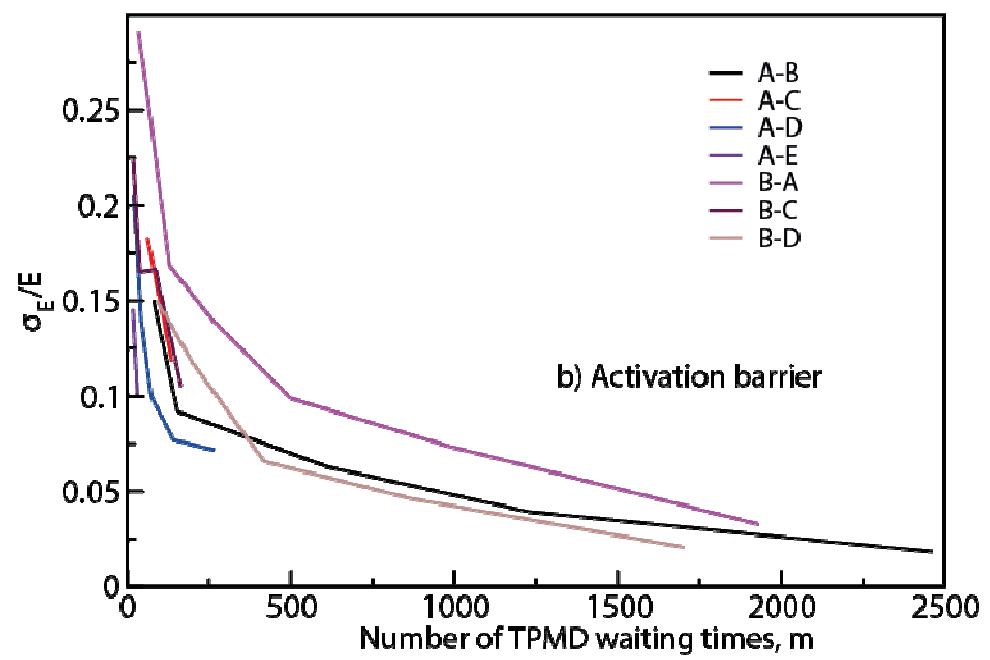
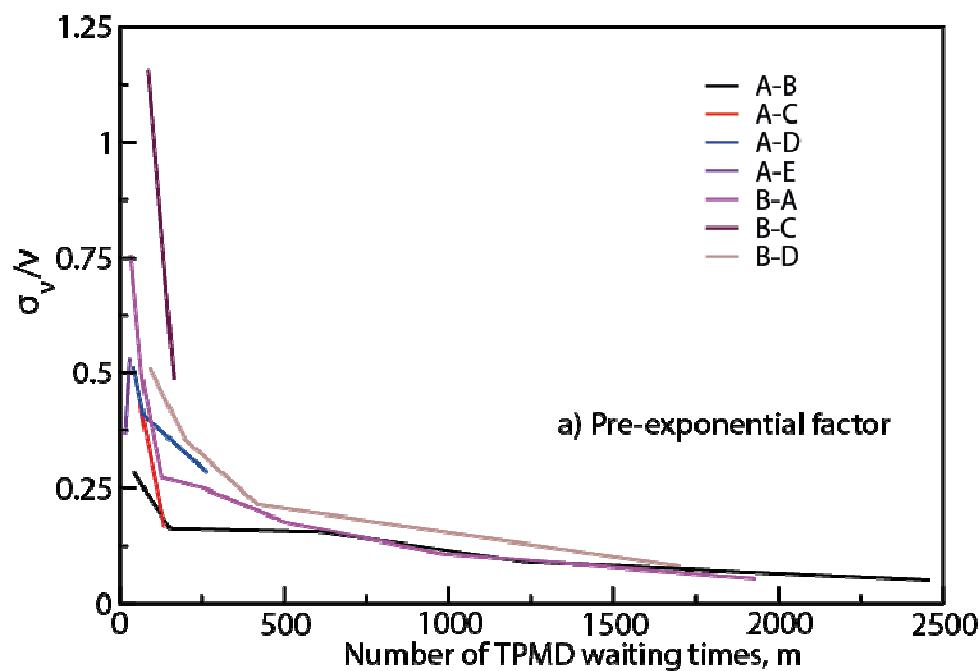
Example: Alanine dipeptide



with Prof. S. Bhattacharya, IIT Guwahati



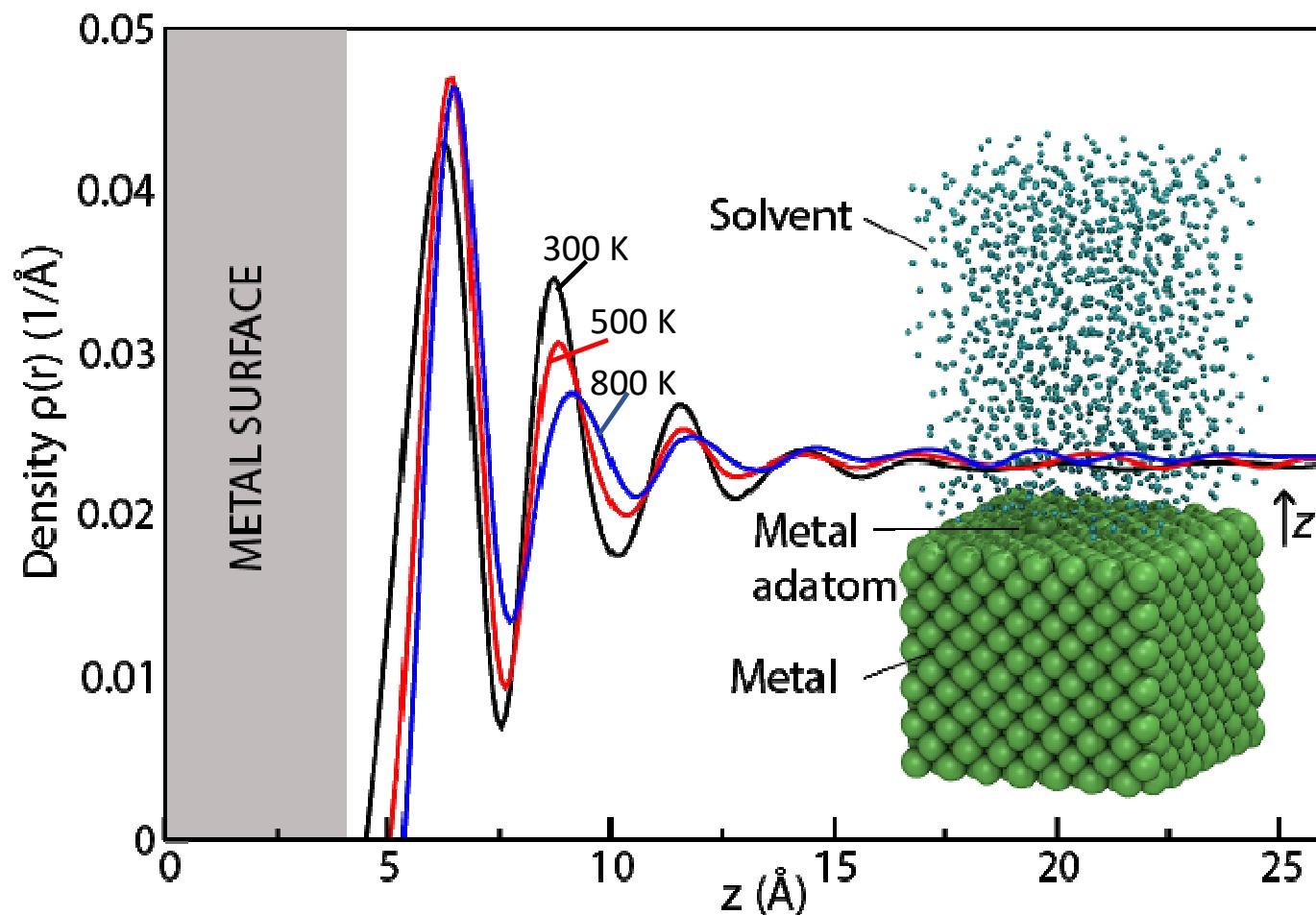
Example: Alanine dipeptide

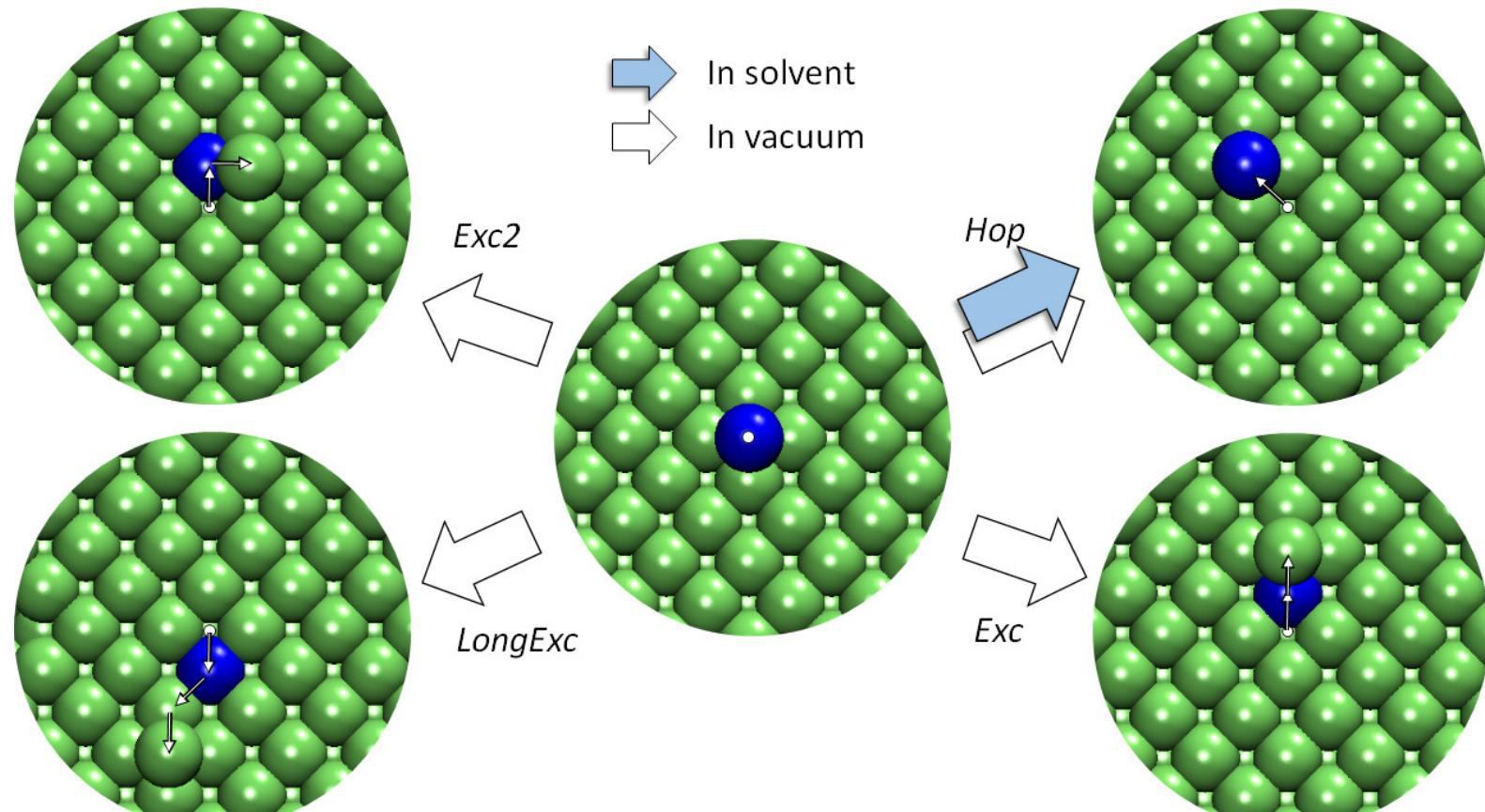


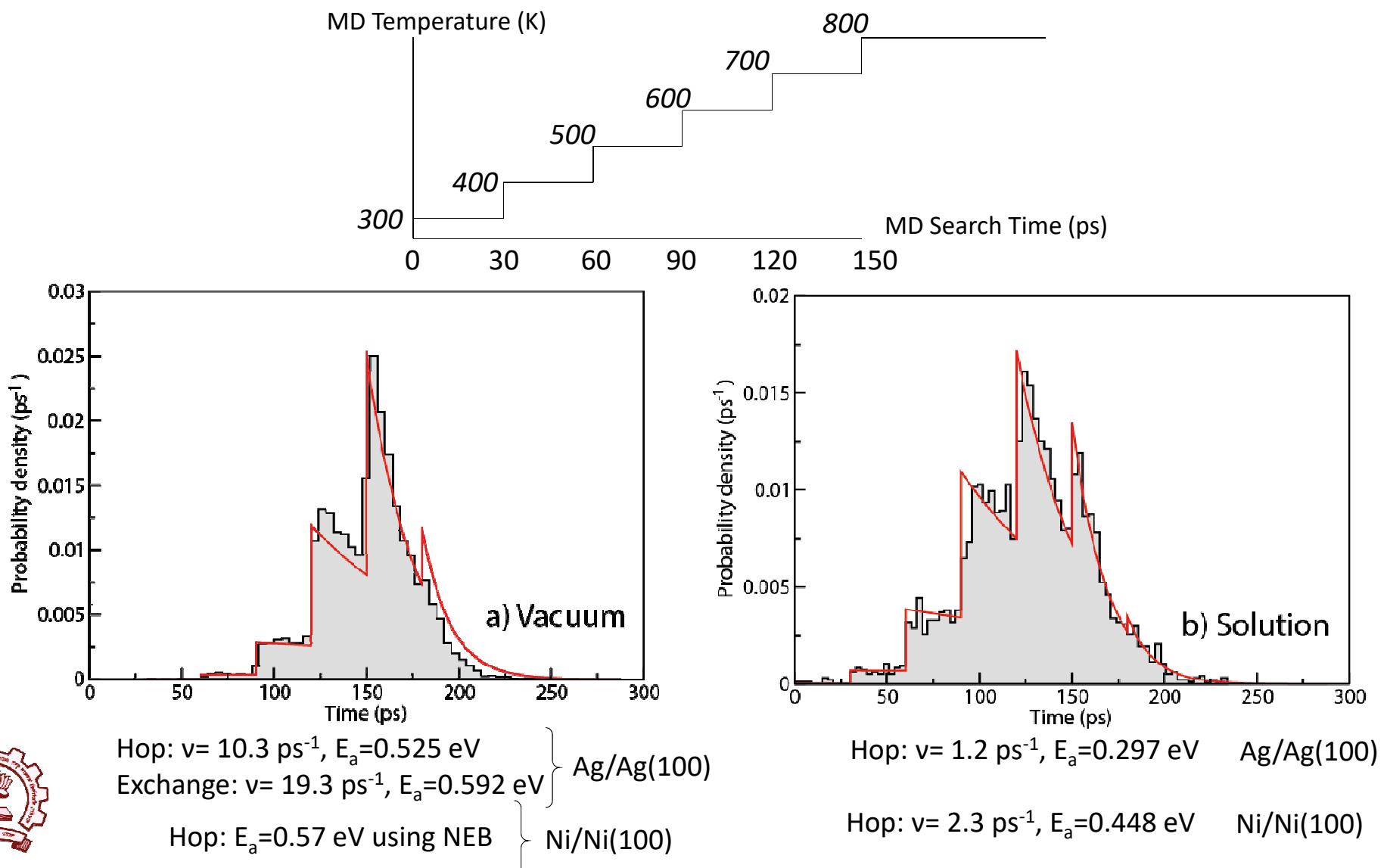
500-2000 waiting times are sufficient

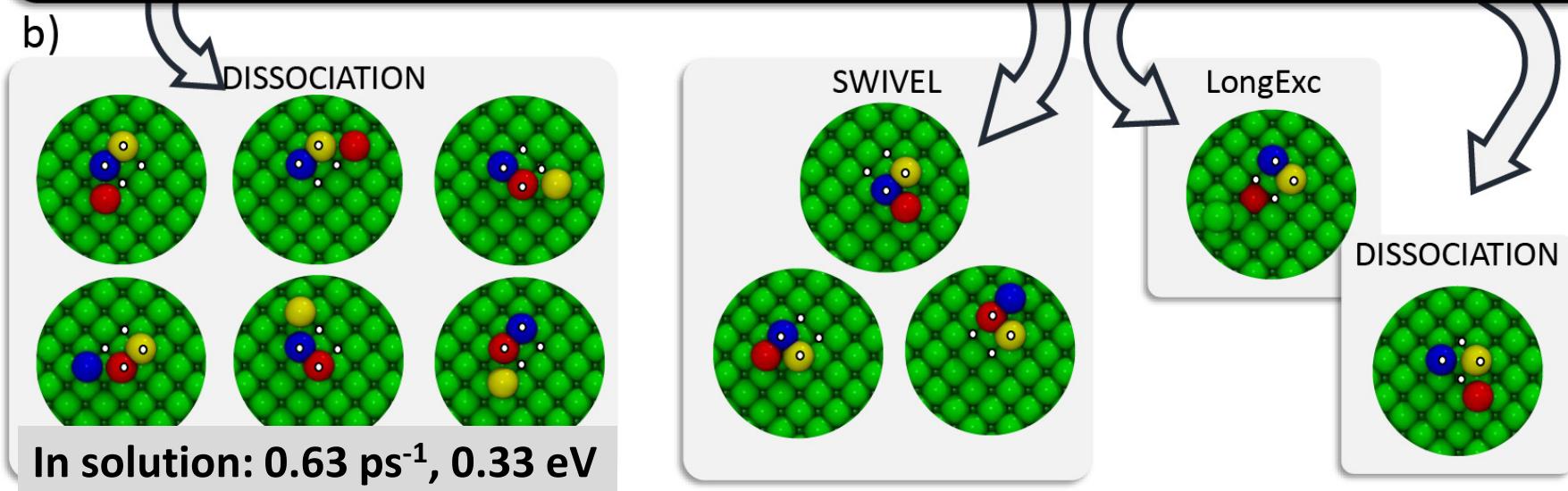
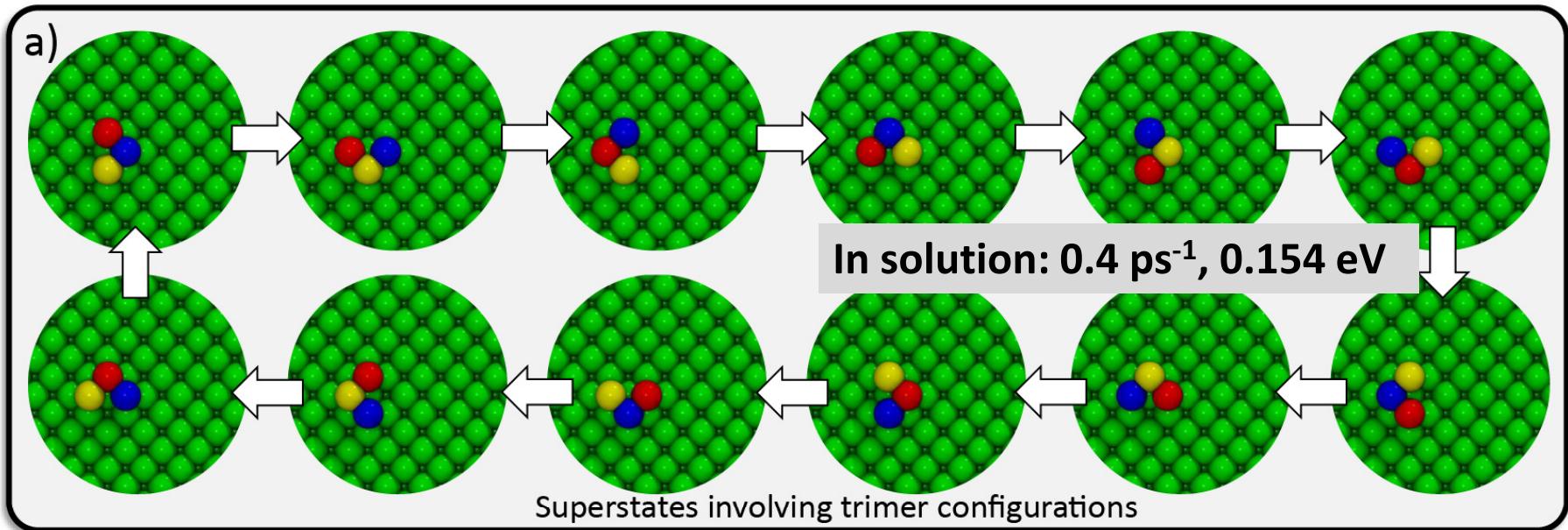


Example: Surface diffusion @ metal-solvent interface









Conclusions

LIST OF FEATURES OF TPMD

- Application to wide range of problems – metals, semiconductor materials, ionic materials, biomolecules
- State recognition allows for off-lattice description
- Rate estimation at multiple temperature for multiple pathways
- Can handle rugged energy landscapes
- Tackle low energy barrier problem, On-the-fly coarse-graining of states possible
- No reaction coordinate/collective variables/minimum energy path
- Automatic construction of local environment KMC models
- Probe Arrhenius behavior (no requirement for HTST)
- Parallelizable to large number of processors
- Orders-of-magnitude time acceleration over MD
- Error control is possible

